60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV_{DSS}	$R_{DS(ON)}$	I_D T_A = +25°C
60V	68mΩ @ V_{GS} = 10V	5.6A
	100mΩ @ V_{GS} = 4.5V	4.7A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Transformer driving switches
- DC-DC converters
- Power-management functions
- Uninterrupted power supplies

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DMN6068SEQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

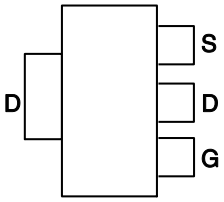
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See diagram below
- Terminals: Finish - Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

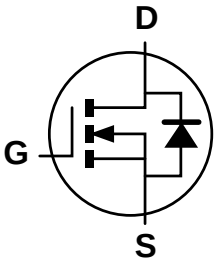
SOT223



Top View



Pin Out – Top View



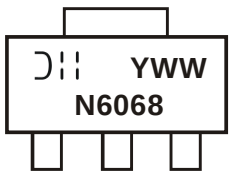
Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
DMN6068SEQ-13	SOT223	4000	Tape & Reel

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



= Manufacturer's Marking
N6068 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Year (ex: 4 = 2024)
WW = Week (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	60	V
Gate-Source Voltage		(Note 5)	V_{GS}	±20	V
Single Pulsed Avalanche Energy		(Note 10)	E_{AS}	37.5	mJ
Single Pulsed Avalanche Current		(Note 10)	I_{AS}	5.0	A
Continuous Drain Current	V_{GS} = 10V	(Note 7)	I_D	5.6	A
		T_A = +70°C (Note 7)		4.5	
		(Note 6)		4.1	
Pulsed Drain Current	V_{GS} = 10V	(Note 8)	I_{DM}	20.8	A
Continuous Source Current (Body Diode)		(Note 7)	I_S	4.9	A
Pulsed Source Current (Body Diode)		(Note 8)	I_{SM}	20.8	A

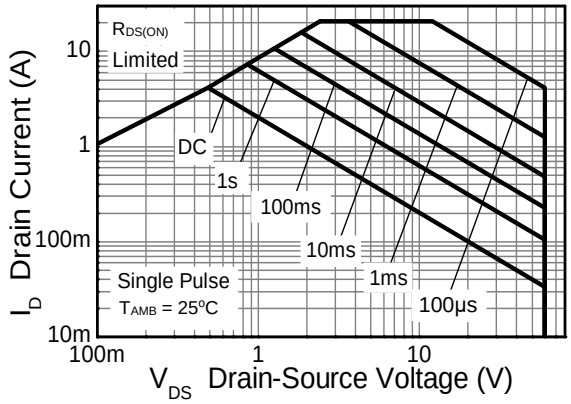
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P_D	2.0	W
Linear Derating Factor			16.0	mW/°C
	(Note 7)		3.7	W
			29.5	mW/°C
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	62.5	°C/W
	(Note 7)		34	
Thermal Resistance, Junction to Lead	(Note 9)	$R_{\theta JL}$	11.5	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

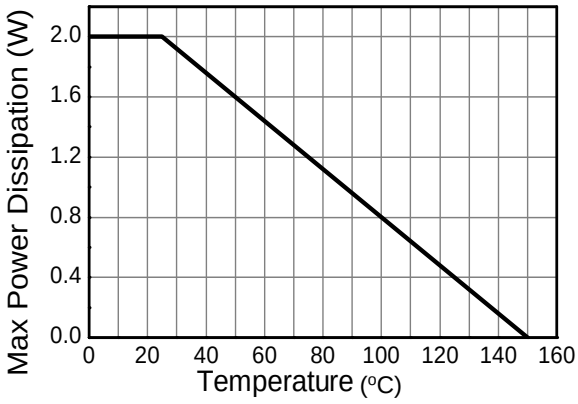
Notes:
5. AEC-Q101 V_{GS} maximum is ±16V.
6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
7. Same as note (3), except the device is measured at t ≤ 10 sec.
8. Same as note (3), except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.
9. Thermal resistance from junction to solder-point (at the end of the drain lead).
10. UIS in production with L = 3.0mH, I_{AS} = 5.0A, R_G = 25Ω, V_{DD} = 50V, starting T_J = +25°C.

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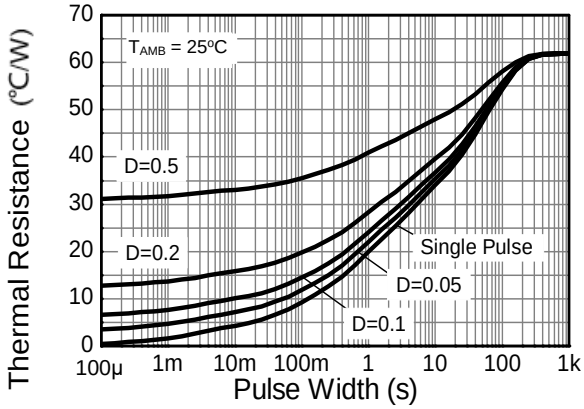
Thermal Characteristics



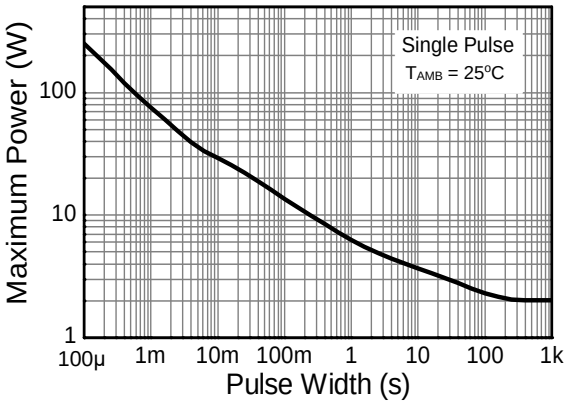
Safe Operating Area



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

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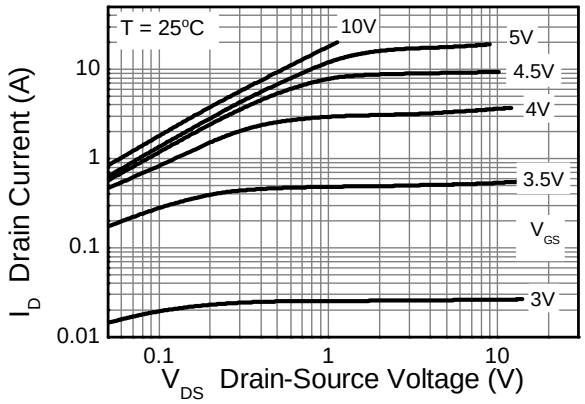
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	60	—	—	V	I_D = 250µA, V_{GS} = 0V
Zero Gate Voltage Drain Current	I_{DSS}	—	—	0.5	µA	V_{DS} = 60V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	1.0	—	3.0	V	I_D = 250µA, V_{DS} = V_{GS}
Static Drain-Source On-Resistance (Note 11)	$R_{DS(ON)}$	—	—	0.068	Ω	V_{GS} = 10V, I_D = 12A
				0.100		V_{GS} = 4.5V, I_D = 6A
Forward Transconductance (Notes 11 & 12)	g_{fs}	—	19.7	—	S	V_{DS} = 15V, I_D = 12A
Diode Forward Voltage (Note 11)	V_{SD}	—	0.98	1.15	V	I_S = 12A, V_{GS} = 0V
Reverse Recovery Time (Note 12)	t_{RR}	—	145	—	ns	I_S = 12A, di/dt = 100A/µs
Reverse Recovery Charge (Note 12)	Q_{RR}	—	929	—	nC	
DYNAMIC CHARACTERISTICS (Note 12)						
Input Capacitance	C_{iss}	—	502	—	pF	V_{DS} = 30V, V_{GS} = 0V f = 1MHz
Output Capacitance	C_{oss}	—	45.7	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	27.1	—	pF	
Total Gate Charge (Note 13)	Q_g	—	5.55	—	nC	V_{GS} = 4.5V; V_{DS} = 30V, I_D = 12A
Total Gate Charge (Note 13)	Q_g	—	10.3	—	nC	V_{GS} = 10V; V_{DS} = 30V, I_D = 12A
Gate-Source Charge (Note 13)	Q_{gs}	—	1.6	—	nC	
Gate-Drain Charge (Note 13)	Q_{gd}	—	3.5	—	nC	
Turn-On Delay Time (Note 13)	$t_{D(ON)}$	—	3.6	—	ns	V_{DD} = 30V, V_{GS} = 10V I_D = 12A, $R_G \cong$ 6.0Ω
Turn-On Rise Time (Note 13)	t_R	—	10.8	—	ns	
Turn-Off Delay Time (Note 13)	$t_{D(OFF)}$	—	11.9	—	ns	
Turn-Off Fall Time (Note 13)	t_F	—	8.7	—	ns	

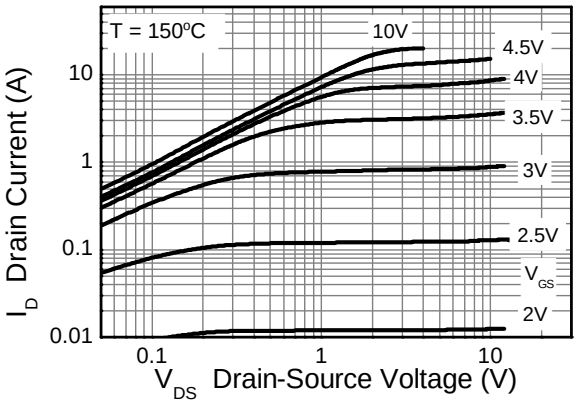
Notes: 11. Measured under pulsed conditions. Pulse width ≤ 300µs; duty cycle ≤ 2%.
12. For design aid only, not subject to production testing.
13. Switching characteristics are independent of operating junction temperatures.

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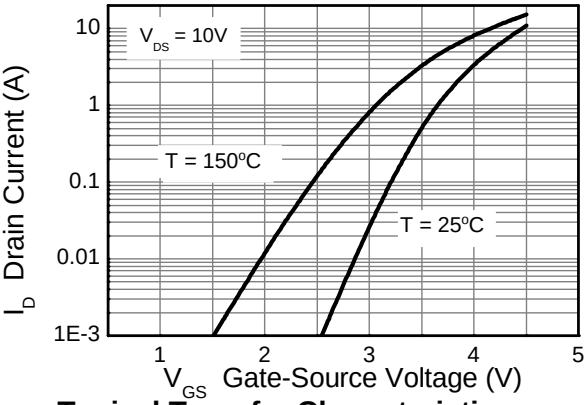
Typical Characteristics



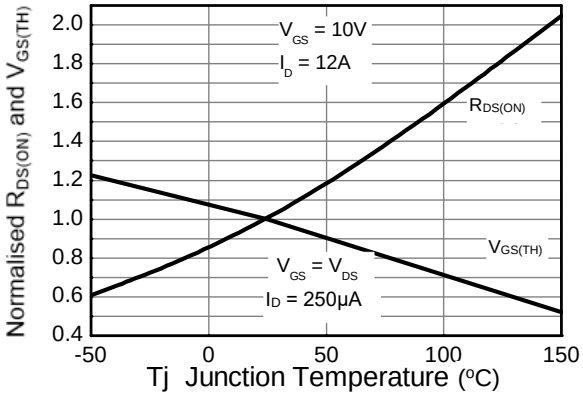
Output Characteristics



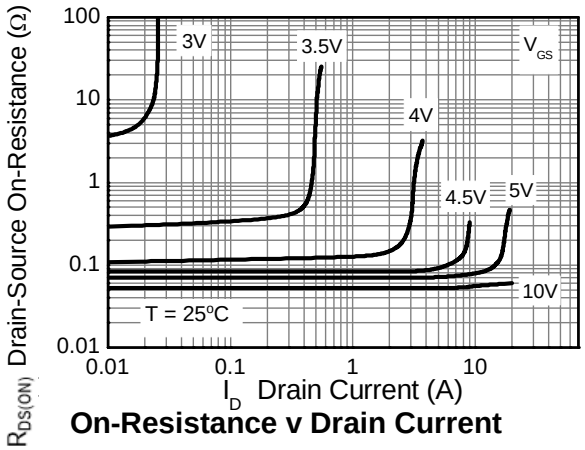
Output Characteristics



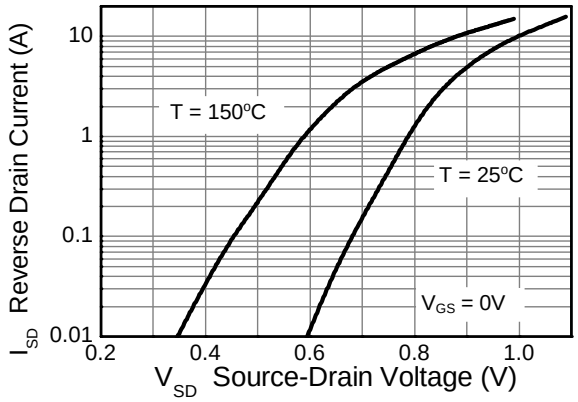
Typical Transfer Characteristics



Normalised Curves v Temperature



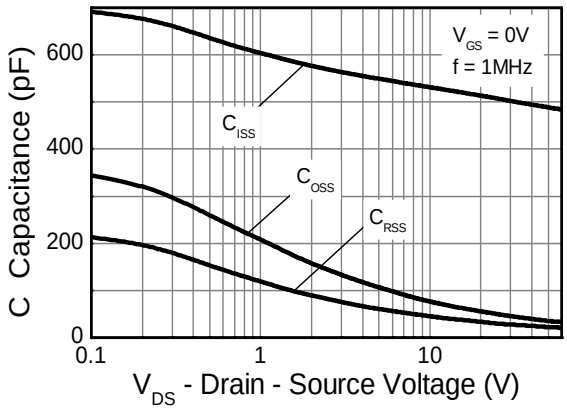
On-Resistance v Drain Current



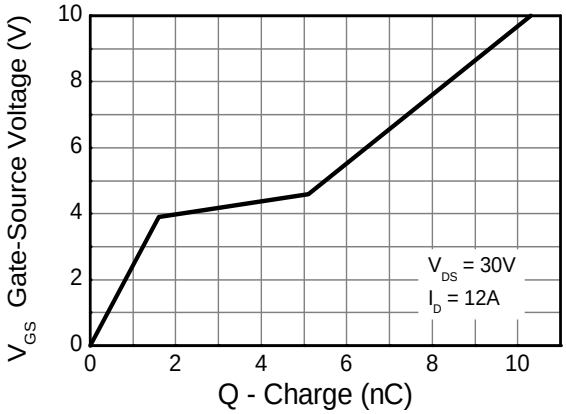
Source-Drain Diode Forward Voltage

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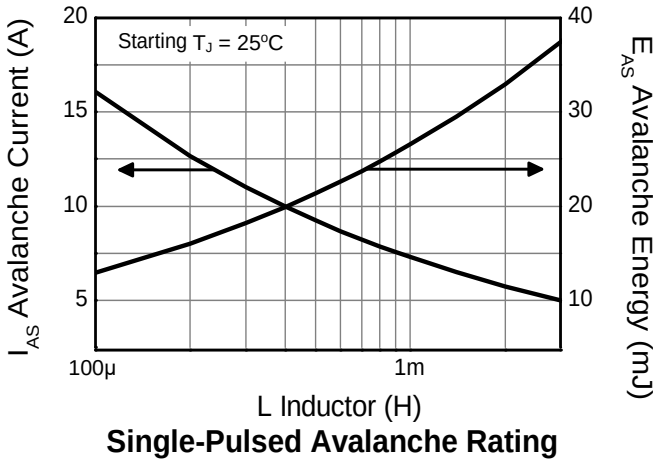
Typical Characteristics (continued)



Capacitance v Drain-Source Voltage



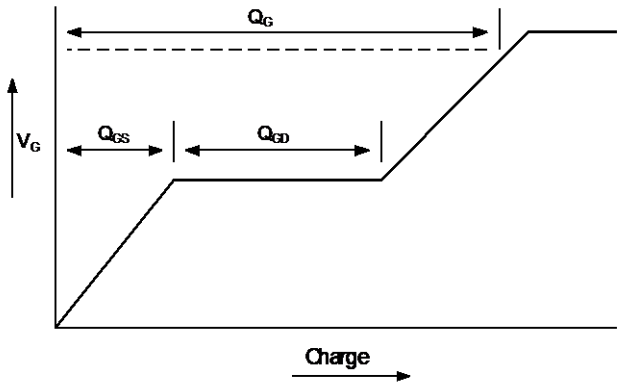
Gate-Source Voltage v Gate Charge



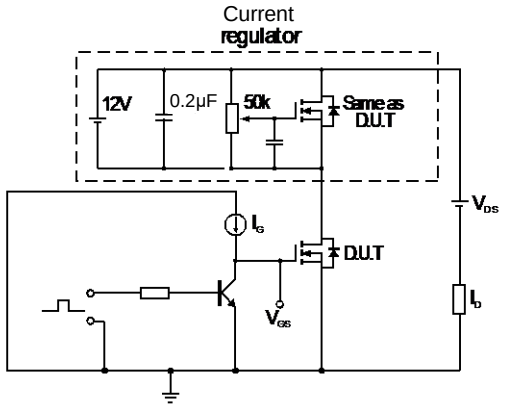
Single-Pulsed Avalanche Rating

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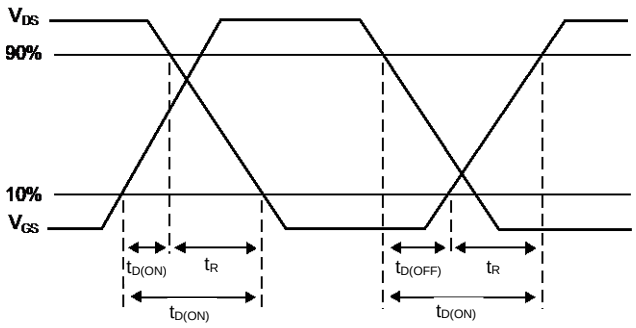
Test Circuits



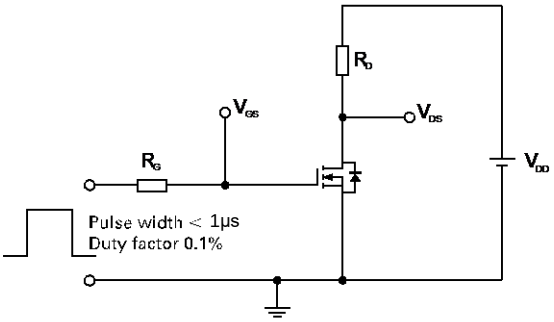
Basic gate charge waveform



Gate charge test circuit



Switching time waveforms



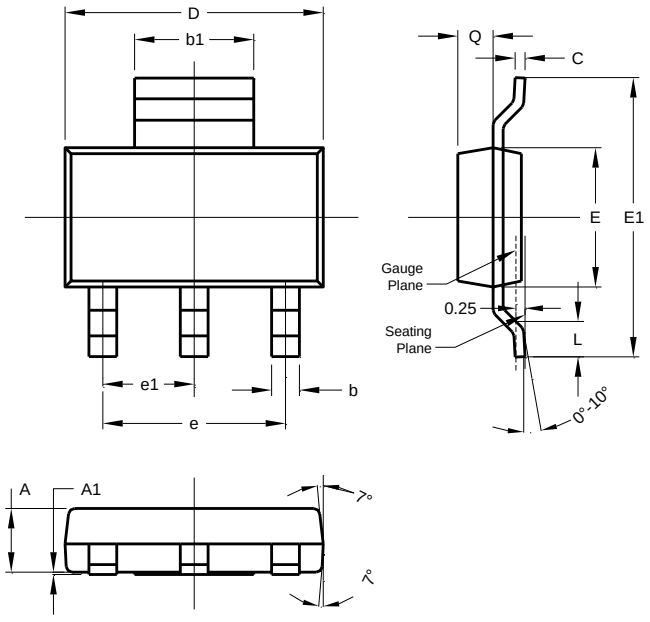
Switching time test circuit

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

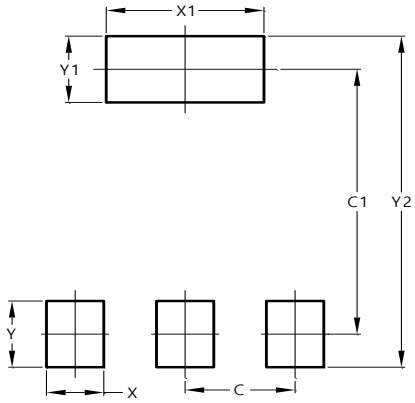


SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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